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Helium-vacancy interactions in vanadium and tantalum

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1. Introduction

The main materials of interest for fission and fusion application are the body centered cubic (bcc) metals [1,2]. Irradiation of bcc transition metals leads to a large number of point defects in the form of self-interstitial atoms and vacancies. The interactions and migrations of defects as well as their absorption at sinks, like dislocations and grain boundaries, can influence microstructural transformations in material which can affect various properties of the metals. Experimental and theoretical studies [3] have shown that the body centered cubic lattice demonstrates improved radiation resistance compared to the close-packed face centered cubic lattice due to reduced amount of vacancy and interstitial defect clustering that occurs directly within displacement cascades as well as higher stacking fault energy. In this paper we will focus on the vacancy clusters and their interactions with Helium atoms in two materials which are good candidates for future fusion systems, V and Ta [4].

V and its alloys are promising candidates as blanket for fusion reactor thanks to their mechanical properties at high temperature and low activation [5,6]. V alloys demonstrate a good combination of strength, ductility and radiation resistance [4,5]. Ta is known for its easy manufacturing, high toughness, high-sputtering threshold energy, and low activation properties which make it a candidate for target material for spallation sources or even first wall material

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ABSTRACT

In this paper we investigate the energy landscape of vacancy clusters in the presence of Helium in two materials, Vanadium and Tantalum. In order to address the relative stability of small vacancy-Helium clusters as well as the basic migration mechanisms we have used Density Functional Theory. The results of calculations are compared to experimental results, when available, and can be systematized in potentially simple laws that can be easily used subsequently in multi-scale techniques including kinetic Monte Carlo and cluster dynamics simulations.

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in fusion reactors [7,8]. As such, study of defects in those two materials, V and Ta serve as the basic foundation for future research regarding structural materials in the fusion industry.

Under irradiation, the structural materials are subject to damages such as swelling [9], embrittlement [10] and blistering [11] triggered, enhanced or suppressed [12] by He resulting of (n, α) transmutation reactions. He atoms are usually trapped at grain boundaries, dislocations or voids [13,14]. The early stages of formation of He bubbles in metals cannot be observed experimentally due to the limited spatial resolution. Ab initio calculations based on Density Functional Theory (DFT) are powerful tools to investigate the processes taking place at the beginning of nucleation of such objects. DFT calculations provide quantitative insight into the nature of clusters containing a small number of defects. About V relevant studies can only be found in the last years while data concerning Ta remains scarce. Hua et al. [15] went to the conclusion that alloying V with Ti enhances migration energy of He and diminishes He-vacancy binding energy. Zhang et al. [16] studied the interaction of He with monovacancy and SIA in pure V and V alloys. They showed that in V alloys, the formation and migration energies of He are larger than in pure V. The same group investigated stability of small He-vacancy clusters and migration of monovacancy. It was found that interstitial He clusters are weakly bound and need vacancy to be stable [17]. The formation of He and vacancy at grain boundary in V has been investigated in Ref. [18]. He-He and He-metal interactions have been studied in various bcc transition metals [19]. Energetics of interstitial He in several metals of *V* group and *VI* group have been detailed in Ref. [20]. Up to







now, however, only a limited number of configurations has been studied. In this study we focus on He-vacancy type clusters in pure V and Ta, in particular we are interested in the first steps of nascent bubbles. To this end, we detail the formation and migration not only of He and monovacancy but also di-vacancies that have been proved to play a significant role in diffusion processes in Fe [21]. In the above-mentioned works, a small amount of clusters have been studied. Attempting to get the most stable clusters, we explore systematically several configurations of each He-vacancy cluster type.

This paper is organized as follows: Section 2 provides the methodology and the details of the employed techniques used for the calculations. In Section 3.1 we present the formation energies computed for vacancy and He-vacancy type clusters. In Section 3.2 the stability of He-vacancy type clusters is investigated. Finally, Section 3.3 describes the migration processes and barriers of vacancy clusters and how helium modifies the diffusion mechanisms.

2. Computational details

Ab initio calculations were performed with density functional theory (DFT) as implemented in the Vienna Ab initio Simulation Package (VASP) [22,23]. We employed non spin-polarised calculations with the generalised gradient approximation (GGA) with the Perdew-Burke-Ernzerhof (PBE) [24] exchange-correlation functional, and semi-core projector-augmented wave (PAW) [25,26] as pseudo-potentials. According to Ref. [19], Van der Waals interactions (\sim 20 meV) can be neglected with respect to He-He and He-metal interactions. Up to 3 vacancies, the bcc supercell of 128 atoms with a $4 \times 4 \times 4$ k-points mesh grid generated by Monkhorst-Pack scheme [27] was used; for more than 3 vacancies we have used a 250 atoms supercell with a $3 \times 3 \times 3$ k-points mesh grid. The Methfessel-Paxton smearing [28] with a 0.25 eV width was used and a 350 eV cutoff energy for both V and Ta case. Atomic positions were relaxed at constant volume until forces on each atom were less than 0.01 eV/Å. The migration barriers and paths were determined using the climbing image nudged elastic band method (CI-NEB) [29,30] with 5 eV/Å² spring constant and a 0.01 eV/Å force convergence threshold. In addition, the converged energy it was corrected by subtracting the elastic dipole interaction energy between self-images due to periodic boundary conditions. We applied the procedure from [31]. In that paper, the elastic dipole-dipole correction is computed from the value of elastic dipole of the defects, which, in first approximation, is proportional to the stress of the simulation box. In order to have reliable value of the elastic dipole, from the stress of the simulation box containing the defect we have extracted the residual stress of the bulk reference. The magnitude of corrections are always smaller than 0.15 eV.

The equilibrium bcc lattice constant obtained for V and Ta was 3.00 Å and 3.32 Å, respectively. Those values are close to experimental data 3.03 Å for V and 3.30 Å for Ta [32].

3. Results

3.1. Formation energy of He_nV_m clusters

The energetics of isolated He in interstitial configurations as well as the vacancy and vacancy-helium clusters inserted in the bcc matrix of V and Ta are investigated.

The formation energy of the simulation box containing n He atoms inserted into the bcc matrix is given by:

$$E_{\mathrm{He}_n}^f = E_{\mathrm{He}_n} - E_0 - n \times E_{\mathrm{He}},\tag{1}$$

 E_{He_n} is the DFT energy of the supercell containing *n* interstitials He, E_0 is the energy of the perfect bulk supercell and, finally, E_{He} is the energy of an isolated He atom. E_{He} (0.014 eV) has been computed with single He atom in a 10 Å × 10 Å × 10 Å box, a 400 eV cutoff energy and a pseudo-potential with 1s² electronic structure. Firstly, we carefully checked the case n = 1 of only one He atom in the bcc matrix. Lately, we will discuss the case n > 1. In V the formation energies for interstitial configurations are 3.12 eV and 3.34 eV for tetrahedral (*T*) and octahedral sites (*O*), respectively. In Ta the same relative stability is found, the interstitial tetrahedral configuration having a formation energy of 3.47 eV, with 0.32 eV lower than interstitial octahedral configuration. For both metals, V and Ta, we found the similar hierarchy in the energy of interstitial configurations, the *T* interstitial site is more stable than the *O* site, as in other bcc transition metals, such as Fe [33], W and Nb [20].

In both metals, V and Ta, we have studied also the relative stability of vacancy clusters (V_m) up to quadri-vacancy (m = 4). Again we have used as indicator the zero K formation energy of clusters. The formation energy of the *m* vacancy cluster, V_m , is defined by:

$$E_{V_m}^f = E_{V_m} - \frac{(N-m)}{N} \times E_0,$$
 (2)

with *N* the number of atoms of the perfect bcc lattice and E_{V_m} the DFT energy of the supercell containing *m* vacancies agglomerated in a cluster. Among many investigated configurations the lowest energy cluster, for the cases m = 2, 3, 4, is found to be the more compact clusters, which are reported in Fig. 1. The formation energies of mono-vacancy (Table 1) are in good agreement with experiments for both V (2.47 eV) [34,35] and Ta (2.88 eV) [34,36,37]. We point here the exception of the di-vacancy cluster. In Ta and V we find that the energy of 2nd nearest neighbour configuration (hereafter noted V_2^{2nn}) is lower than the energy of 1st nearest neighbour configuration (hereafter denoted V_2^{1nn}). The formation energy of V_2^{2nn} is lower than the formation energy of the configuration V_2^{1nn} by 0.19 eV and 0.24 eV in V and Ta, respectively (Table 1). The same tendency is observed for all VIB group and VB group metals and iron for which the most stable configuration of di-vacancy is the V_2^{2nn} . In V and Ta, the binding energy of di-vacancy, in both configurations, V_2^{1nn} and V_2^{2nn} , is positive, indicating the attraction between mono-vacancies in order to form the di-vacancy. The same tendency for the di-vacancy energy landscape is observed in iron and



Fig. 1. The configurations of vacancy clusters ($V_m, m = 1, 2, 3, 4, 5$) with the lowest formation energy. Vacancies are represented by cubes while the atoms of the bcc lattice are represented with spheres. For the case of di-vacancy we show the first nearest neighbour (V_2^{1nn}) and the second nearest neighbour configuration V_2^{2nn} : (a) V_1 , (b) V_2^{1nn} , (c) V_2^{2mn} , (d) V_3 , (e) V_4 , (f) V_5 .

	V						Та						
n	m												
	0	1	2 (1nn)	2 (2nn)	3	4	0	1	2 (1nn)	2 (2nn)	3	4	
0		$\begin{array}{c} 2.47 \\ (2.1 \pm 0.2)^a \\ (2.2 \pm 0.4)^b \end{array}$	4.69	4.50	6.46	8.07		$\begin{array}{c} 2.88 \\ (2.8 \pm 0.6)^{a} \\ (3.1)^{c} \\ (2.9 \pm 0.4)^{d} \end{array}$	5.66	5.42	7.97	9.96	
1	3.12	4.47	6.15	6.06	7.58	8.88	3.47	4.66	6.89	6.92	8.77	10.44	
2	6.16	6.26	7.54	7.94	8.90	9.81	6.84	6.49	8.22	8.40	9.97	11.31	
3	9.15	8.15	9.18	9.74	10.09	10.84	10.00	8.63	9.69	10.07	11.09	12.28	
4	12.03	10.01	10.92	11.48	11.74	11.92	13.26	10.79	11.22	11.80	12.29	13.31	
5		11.91	12.47	13.45	12.99	13.20			12.84	14.19	13.81	14.46	
6		13.73	14.44	15.07	14.62	14.76		14.87	14.80	15.69	15.39	15.62	

The lower limit of formation energy (in eV) of He_n V_m clusters, extracted from the present calculations, using Eq. (3), for small values of n and m.

^a Experimental data from Ref. [34].

Table 1

^b Experimental data from Ref. [35].

^c Experimental data from Ref. [36].

^d Experimental data from Ref. [37].

is at variance with *VIB* metals, such as Mo and W [38–43], for which the first nearest neighbour configuration is slightly attractive while the second nearest neighbour configuration is strongly repulsive.

The formation energy for mixed He-vacancy clusters, He_nV_m (up to n = 26 for m = 4), is defined as:

$$E_{\operatorname{He}_{n}V_{m}}^{f} = E_{\operatorname{He}_{n}V_{m}} - \frac{(N-m)}{N} \times E_{0} - n \times E_{\operatorname{He}},$$
(3)

where $E_{He_nV_m}$ is the DFT energy of the supercell containing the He_nV_m cluster. The morphology and construction of all possible clusters for a given number of n He atoms and m vacancies is not simple task. The number of possible choices grows exponentially with the number of defects. The exhaustive search is difficult and consequently several hypotheses are made in order to choose the geometries of the lowest energy configurations. Firstly, we investigated only geometrically compact configurations. The only exception was the di-vacancy for which the two configurations first and second nearest neighbours have been chosen. Secondly, for any given He_nV_m cluster the *n* He atoms randomly decorate the most stable V_m clusters, deduced previously and presented in Fig. 1. Therefore, for a cluster He_nV_m tens of random positions have been picked for the n He atoms. These atoms are placed in T, O or substitutional (S) sites in the neighborhood of the m vacancies. For Ta, we reduce the sampling up to ten configurations, as we will see later, He atoms prefer to occupy S sites and many initial configurations collapse to the same minimum. Nevertheless, since we restrict the sampling, there is no guarantee that we will find the most stable clusters. This is critical in particular for the largest clusters, which are beyond the scope of this paper. However, for the smallest clusters, which are the object of the present paper, we are reasonably confident in finding the lowest energy configurations.

In V, the lowest energy mixed configuration He_1V_1 is given by the He atom slightly off *O* site, as it presented in Fig. 2 with the formation energy of 4.47 eV. The *S* configuration is higher in energy with 0.21 eV. In Ta, the *S* site is the only found stable configuration. In this Ta case, all calculations having as the initial position as *T* and *O* position of He are finally relaxed into the *S* configuration.

In the most stable configuration of clusters with 2 He atoms, He_2V_1 , Helium atoms and the vacancy are aligned along the $\langle 111 \rangle$ direction for both metals, V and Ta. In case of He_3V_1 cluster, the He atoms form an equilateral triangle centered on the vacancy in V, while in Ta, one He atom is shifted toward the vacancy and the 2 others occupy positions close to 0 sites (Fig. 2c). The geome-

try of clusters with the lowest formation energy from n = 4 to n = 6 have all He atoms close to *O* sites in both V and Ta case.

In V, for He₁V₂ (Fig. 3), the 1*nn* configuration has higher formation energy than in the 2*nn* configuration, as in the case of V₂. However, the difference is reduced to 0.09 eV compared to 0.19 eV in the pure di-vacancy cluster (Table 1). Adding more He around the di-vacancy, the relative stability of mixed configurations He_nV₂, having the di-vacancy in 1*nn* and 2*nn* positions, is reversed. For $n \ge 2$ the formation energy of the 1*nn* configuration becomes lower than the corresponding formation energy in the 2*nn* position. In Ta, except for the case of di-vacancy without He, the formation energy of He_nV₂²ⁿⁿ clusters is systematically lower than for the He_nV₂²ⁿⁿ. Furthermore, the energy difference between these two cluster types is larger when adding more He atoms.

In general, comparing the energy landscape of He in the neighborhood of the vacancy in V and Ta, it can be noted that the *S* site is attractive in Ta while it is repulsive in V (Figs. 2 and 3). A similar result has been found in a previous work [20]. This tendency is explained by a larger charge density in vacancy sites in V than in Ta. Vacancy charge density has a repulsive interaction with the atomic charge density of He. So He will have a stronger repulsive interaction at *S* site in V, increasing the formation energy enough to make this configuration unstable. As a result in the most stable configuration, He is shifted toward *O* site.

In order to investigate the energetical cost to form $He_{n+1}V_m$ clusters, we take for each cluster type the lowest formation energy found in our sampling. For all types of clusters He_nV_m , the cost in energy to form $He_{n+1}V_m$ increases linearly with *n* but the slope decreases with *m* (see Fig. 4). Due to random sampling of He_nV_m configuration, for given value of m = 2, 3, there are some uncertainties in the slope. The acceptable range in the value of the slope are marked in Fig. 4. The linear increase of formation energy with n can be explained by the fact that a He atom is weakly bound to He_n clusters whereas He-vacancy binding energy is 1-2 orders of magnitude larger (Table 2). Hence, adding a He atom in the vacancy neighborhood results in adding one more He-vacancy interaction, until the vacancy is filled with He. The slope decreases with msince He atoms have more space to maximize He-He distance. According to [19], for group VB metals such as V and Ta, He-He interaction is weaker than for group VIB of transition metal (W, Mo) while the He-He distance is larger. As a consequence, for smaller clusters, one can expect a clearer inflection in the linear law for metals of group VIB than for group VB.

W. Unn-Toc et al./Computational Materials Science 145 (2018) 197-207



Fig. 2. The configurations of lowest formation energy of mixed He_nV_1 clusters in V and Ta. (a) He_1V_1 , (b) He_2V_1 , (c) He_3V_1 , (d) He_4V_1 , (e) He_5V_1 , (f) He_6V_1 . Vacancy is represented with yellow cube. When the He atom is placed in the substitutional site, *S*, the corresponding vacancy is not shown. The light blue spheres are used for He atoms illustration. The bcc matrix atoms are represented with grey spheres for the cases when the same lowest energetic He-vacancy cluster configuration is obtained for complexes embedded into Ta and V, i.e. the cases *b*, *d*, *e*, and *f*. For the cases *a* and *c* the most stable cluster is different for the two host metals and the grey and dark blue balls are used for V or Ta atoms. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)



Fig. 3. The geometries of the lowest formation energy clusters of the type He_nV_2 in V (grey bcc lattice) and Ta (blue bcc lattice). The geometry of the di-vacancy clusters are taken in the 1nn and 2nn configurations. (a) $He_1V_2^{1m}$, (b) $He_2V_2^{1m}$, (c) $He_3V_2^{1m}$, (d) $He_4V_2^{1m}$, (e) $He_1V_2^{2m}$, (f) $He_6V_2^{2m}$, (g) $He_3V_2^{2m}$, (h) $He_4V_2^{2m}$. Vacancy and the He impurities are represented with yellow cube and light blue spheres, respectively. When the He atom is placed in the *S* site the corresponding vacancy cube is not shown. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

3.2. Stability and binding energies of He-vacancy clusters

We investigated the stability of pure He and vacancy clusters and He-vacancy complexes looking at their binding energy to helium atom and mono-vacancy given respectively by:

$$E_{\text{He}-\text{He}_{n}V_{m}}^{b} = E_{\text{He}_{l}} + E_{\text{He}_{n-1}V_{m}} - E_{\text{He}_{n}V_{m}} - E_{0}$$
(4)

and

$$E_{V-\text{He}_{n}V_{m}}^{b} = E_{V_{1}} + E_{\text{He}_{n}V_{m-1}} - E_{\text{He}_{n}V_{m}} - E_{0},$$
(5)

where E_{He_1} is the total energy of the bcc supercell in which is inserted an interstitial He at *T* or *S* site for V and Ta, respectively. E_{V_1} is the total energy of the bcc supercell with one monovacancy. Binding energy of He/vacancy is the amount of energy necessary to escape from cluster. Following Eqs. (4) and (5), positive binding energy corresponds to an attractive interaction for He and vacancy, respectively. Therefore, clusters with the highest binding energy are more stable.

Fig. 5 emphasizes a general overview of the binding energy of one He atom in clusters He_nV_m for V and Ta. All clusters that have been considered (not only the most stable ones) are shown. Firstly,



Fig. 4. Formation energy (in eV) of clusters He_nV_m as a function of n, in V and Ta. Among all the possible values of formation energies, for various He_nV_m configurations at given n and m, only the lowest formation energies of each cluster type have been reported. For di-vacancy clusters the labels 1nn and 2nn stand for di-vacancy configurations in first nearest neighbours and second nearest neighbours, respectively. The table gives the slope for each type of cluster, at fixed m. In the case when two values are presented, we give the upper and lower limit of possibles choices of slope.

Table 2 The upper limit of binding energy (in eV) of He to He_nV_m clusters, extracted from the present calculations, using Eq. 4, for small values of *n* and *m*.

				V					1	`a			
n	m												
	0	1	2 (1nn)	2 (2nn)	3	4	0	1	2 (1nn)	2 (2nn)	3	4	
1	0.01	1.12	1.64	1.50	2.01	2.32	0.01	1.75	2.22	1.95	2.66	2.97	
2	0.09	1.34	1.73	1.24	1.81	2.21	0.06	1.62	2.00	1.98	2.25	2.58	
3	0.14	1.24	1.49	1.33	1.94	2.10	0.30	1.32	2.11	1.77	2.33	2.49	
4	0.24	1.26	1.39	1.38	1.48	2.04	0.20	1.29	1.92	1.72	2.25	2.42	
5		1.23	1.58	1.16	1.87	1.85			1.84	1.07	1.93	2.31	
6		1.30	1.16	1.51	1.50	1.57			1.49	1.95	1.87	2.29	



Fig. 5. Binding energy of He to He_nV_m clusters as a function of *n* in V (left panel) and Ta (right panel).

it should be noted that the distribution in He binding energy for the same type of cluster, i.e. fixed number of n and m, is rather broad. The scattered values of the binding energy indicate a strong dependence on the cluster morphology. For each pair of n and mthere is a wide variety of clusters in which He is strongly or weakly bound. For practical use, e.g. kinetic simulations such as Object/ Event Kinetic Monte Carlo [44] or cluster dynamics simulations [45,46], differences of cluster free energies, taking into account configurational entropy, should be used to get proper agreement with Atomistic Kinetic Monte Carlo [45,47]. As a first approximation, configurational entropy can be ignored and this binding free energy can be written as a difference of energies of most stable

configurations. In V, considering the most stable clusters, the binding energy of He in pure He_n clusters ranges from 0.01 eV to 0.24 eV, slowly increasing with the amount of He at least up to n = 4. A similar behaviour is obtained in the case of Ta. We note that in V and Ta the binding energy of He in He₄ clusters is almost 4 times lower than for the similar clusters in Fe (~1 eV) [33]. Adding more He in interstitial clusters He_n at least up to n = 4, amplifies lattice distortion so that, the increasing pressure may lead various processes such as the creation of Frenkel pair as predicted in Fe [48– 50] and observed in Ni [51] and Au [52]. However, is this conclusions should be supported only by supplementary calculations, such as interstitial energetic landscape, which are beyond the goals of this paper.

The upper limit of the He binding energy in He_nV_m , at given n, increases with the number of vacancies. This tendency can be remarked from Table 2. A second trend is that for given m, the He binding energy seems to decrease with n, especially for V_3 (Fig. 5) With the increase of n we expect an increase in the He pressure inside the cavity. Therefore, spontaneous emission of He or self-interstitial, V or Ta atoms, may occur for large n/m ratio [53,54]. This behaviour has been observed at low temperature by Fedorov [55] in V and V alloys, and also theoretically predicted in Fe by Morishita [49].

However, a closer look at Fig. 5 reveals that for m = 1, in V, the binding energy seems to saturate (up to n = 6) indicating that more He atoms can be added before internal pressure reaches a threshold such that significant drop in the binding energy occurs. The present observations are in agreement with previous calculations which have showed that the mono-vacancy clusters containing tens of He atoms still have attractive interaction with He in V [56]. This apparent drop in the binding energy with *n* may reflect the fact we missed more stable clusters in our sampling. In the di-vacancy case, we see that He makes the $He_nV_2^{1nn}$ clusters more stable than the $He_n V_2^{2nn}$ ones whereas the opposite situation is observed without He. In both V and Ta, $He_8V_2^{1nn}$ seems particularly stable compared to $He_7V_2^{1nn}$ and $He_9V_2^{1nn}$. In the $He_8V_2^{1nn}$ cluster He atoms occupy high symmetry interstitial sites O and T while the position of He is more shifted from O and T sites in $He_7V_2^{1nn}$ and $He_9V_2^{1nn}$. Likewise, in V, $H_{20}V_4$ clusters are unstable, contrary to $He_{19}V_4$ and $He_{21}V_4$ clusters for which more high symmetry sites are occupied by He atoms.

The binding energy of a vacancy to pure vacancy clusters V_m increases with the number of vacancies from 0.27 eV for m = 2 to 0.88 eV for m = 4 in V (Fig. 6). It seems to reach a plateau at m = 4 around 0.87 eV. Similar trend has been reported in Fe, using molecular dynamics simulations with different empirical poten-

tials, for which the binding energy saturates slightly above 1 eV for $m \gtrsim 20$ [49].

From the values presented in Table 3, the presence of He atoms in vacancy clusters enhances the binding energy to mono-vacancy, reflecting the fact that He stabilizes vacancy type clusters [33,49]. We find again $\text{He}_n V_2^{1nn}$ are more stable than $\text{He}_n V_2^{2nn}$ for $n \ge 2$ and $n \ge 1$ in V and in Ta, respectively.

3.3. Migration energy barriers

The diffusion processes of interstitial He and vacancy are important in order to understand the mechanism of cluster nucleation and growth during the primary stages. In the following, we restrict the scope of migration of vacancies toward their 1st nearest neighbour, i.e. in $\langle 111 \rangle$ direction. To reveal the minimum energy path (MEP) of migrations mechanism involving vacancy-He complexes is not obvious. We have tried two steps procedure. Firstly, we divided the unrelaxed path between the initial and final configuration in several segments. The most stable configurations found along these segments were taken as intermediate steps in order to precondition the finding MEP algorithm. Secondly, by fixing the initial and final configurations we let the minimization algorithm to find the MEP. We retain the path with the lowest energy barrier.

3.3.1. Vanadium

The interstitial He diffusion is studied by examination of two paths which connect the lowest energy configurations: *T* site to *T* site, and *T* site to *O* site. The $T \rightarrow T$ mechanism corresponds to a migration barrier of 0.12 eV in V (Table 4). This migration barrier is in good agreement with TDS experiments for which the value of 0.13 eV is reported [55]. It should be noted that the migration barrier of this mechanism is twice as high as in Fe [33]. The migration barrier of 0.26 eV. Consequently, the interstitial He prefers to diffuse via first neighbor *T* sites. The same conclusion was drawn in Fe [33].

The DFT migration barrier of the mono-vacancy is found equal to 0.48 eV. This value is in agreement with TDS experiments of Fedorov [55], 0.5 eV, and van Veen, 0.47 eV [57]. The di-vacancy migration barrier from the V_2^{1nn} state (Fig. 1b) to V_2^{2nn} configuration (Fig. 1c) is asymmetrical, with 0.34 eV and 0.58 eV for forward and reverse jumps, respectively. Another possible migration of di-vacancy is the direct mechanism path from a V_2^{2nn} to another V_2^{2nn} configuration. This barrier has the value of 0.37 eV. This di-vacancy mechanism implies two migration steps by dissociation-association. One of the vacancy dissociates from the V_2^{2nn} cluster



Fig. 6. Binding energy of vacancy, V_1 , to He_n V_m clusters as a function of m in V (left panel) and Ta (right panel).

Ta	hl	P	3

The upper limit of binding energy (in eV) of vacancy to $He_n V_m$ clusters, extracted from the present calculations, using Eq. (5), small values of n and m.

			V			Та						
n	m											
	1	2 (1nn)	2 (2nn)	3	4	5	1	2 (1nn)	2 (2nn)	3	4	
0	0.00	0.27	0.51	0.43	0.87	0.88	0.00	0.26	0.50	0.40	0.97	
1	1.11	0.79	0.89	0.94	1.17		1.74	0.73	0.70	1.11	1.28	
2	2.37	1.19	0.79	1.50	1.57		3.31	1.11	1.06	1.39	1.61	
3	3.47	1.43	0.88	2.12	1.72		4.33	1.90	1.51	1.94	1.77	
4	4.49	1.56	1.00	2.22	2.28		5.43	2.52	1.94	2.47	1.93	
5		1.91	0.92	2.93	2.25					3.33	2.32	
6		1.76	1.13	2.92	2.32			3.02	2.14	3.26	2.73	

Table 4

DFT migration energy barrier, E^m (in eV), for He, vacancy (V_m) and He-vacancy (He_nV_m) clusters in V and Ta. The theoretical values of the migration barriers are compared, when possible, to the corresponding experimental values. 1*nn* and 2*nn* denote the first and second nearest neighbor configuration of di-vacancy, respectively.

Configuration		V		Та					
	Path	E^m (eV)	Exp. (eV)	Path	E^m (eV)	Exp. (eV)			
He interstitial									
He	$T \rightarrow T$	0.12	0.13 [55]	T o T	0.18				
	$T \rightarrow 0$	0.26		$T \rightarrow O$	0.40				
V _m clusters									
Mono-vacancy	1nn	0.48	0.5 [55,60]	1nn	0.72	0.7 [61,60]			
			0.47 [57]						
Di-vacancy	$1nn \rightarrow 2nn$	0.34		$1nn \rightarrow 2nn$	0.63				
Di-vacancy	$2nn \rightarrow 1nn$	0.58		$2nn \rightarrow 1nn$	0.87				
Di-vacancy	$2nn \to 2nn$	0.37		$2nn \to 2nn$	0.55				
He_nV_m clusters									
He_1V_1	1nn	1.27		1nn	1.89				
He_1V_2	$1nn \rightarrow 2nn$	0.79		$1nn \rightarrow 2nn$	1.14				
He_1V_2	2nn ightarrow 1nn	0.88		$2nn \rightarrow 1nn$	1.12				
He ₁ V ₂	$2nn \to 2nn$	0.66		$2nn \to 2nn$	1.12				



Fig. 7. Di-vacancy migration along $V_2^{2nn} \rightarrow V_2^{2m}$ path in V. Vacancies are represented with yellow cubes and V atoms with grey balls. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

to reach its 1st nearest neighbour position along the $\langle 111 \rangle$ direction. At this point the two vacancies are in a 4th nearest neighbour configuration (Fig. 7b). Then the second vacancy that jump along $\langle 111 \rangle$ direction and associates with the first vacancy to form again the V_2^{2nn} cluster (Fig. 7c). It should be mentioned that a direct jump from configuration presented in Fig. 7a to configuration of Fig. 7c dissociates similarly, following the mechanism described above.

The influence of He on vacancy diffusion is considered using the same NEB algorithm. As in previous cases the minimum energy path of HeV₁ cluster is searched by fixing the initial and final states in the corresponding lowest energy configurations. We found that the migration of HeV₁ cluster is a two steps mechanism: (i) the He atom jumps from initial *O* site to final 3rd nearest neighbour *O* site, hopping through 1st nearest *T* sites (this mechanism is schematized in Fig. 8a–c) and (ii) the vacancy migrates along $\langle 111 \rangle$ direction and He hops from *T* to *O* site to reach their final position (Fig. 8d and e). The computed DFT migration barrier is about 1.27 eV, which corresponds roughly to the He-vacancy binding energy plus migration barrier of He ($T \rightarrow T$). As a result, He

increases the diffusion barrier of mono-vacancy by 0.67 eV. This dissociative mechanism has been also experimentally inferred [58,59] from He implanted depth profiles and He thermal desorption experiments at low temperature.

The di-vacancy in the presence of He can migrate from He₁ V_2^{1nn} into He₁ V_2^{2nn} configuration by passing a 0.79 eV barrier. Migration from He₁ V_2^{2nn} to He₁ V_2^{2nn} configuration has a lower barrier (0.66 eV) compared to the previous He₁ $V_2^{1nn} \rightarrow$ He₁ V_2^{2nn} path. The He₁ $V_2^{2nn} \rightarrow$ He₁ V_2^{2nn} process is a two steps mechanism which is schematized in Fig. 9a–d. Firstly, one vacancy of the cluster dissociates to reach first nearest neighbour site in the $\langle 1\,1\,1 \rangle$ direction. The geometry of the cluster is changed into a slightly shifted V_2^{1nn} configuration (Fig. 9b). Secondly, the second vacancy moves to its nearest neighbour in the same $\langle 1\,1\,1 \rangle$ direction. Simultaneously the He atom jumps to final *O* position between the two vacancies, similar to the initial configuration (Fig. 9c–e). The trapped He atom roughly doubles the migration barrier of the di-vacancy for both $V_2^{1nn} \rightarrow V_2^{2nn}$ and $V_2^{2nn} \rightarrow V_2^{2nn}$ paths, and increases the barrier by



Fig. 8. Migration of He_1V_1 cluster in V. The initial and final configurations are presented in the frames a and e, respectively. The intermediate steps of migration are presented in the frames b–d. Vacancy, V and He atoms are represented with yellow cubes, grey and light blue balls respectively. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)



Fig. 9. Migration of He_1V_2 cluster in V. The initial and final configurations are presented in the frames a (*O* site) and e (*O* site), respectively. The intermediate steps of migration are presented in the frames b–d. Vacancy, V and He atom are represented with yellow cube, grey and light blue ball, respectively. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

50% of the $V_2^{2nn} \rightarrow V_2^{1nn}$ path. In the presence or not of the He the barrier energy of mono-vacancy remains higher than for divacancy. However, the presence of He atom increases the gap between mono-vacancy and di-vacancy energy barrier.

3.3.2. Tantalum

The migration barrier of interstitial He in Ta lattice is reported in Table 4. The migration barrier of interstitial He are 0.18 eV and 0.40 eV for the $T \rightarrow T$ and $T \rightarrow O$ paths, respectively. Therefore the lowest energy migration mechanism corresponds to the $T \rightarrow T$, similar to the V case.

The value of migration barrier of mono-vacancy in Ta is 0.72 eV. This result is consistent with resistivity recovery experiments which give the value of 0.7 eV [61]. The lowest migration barrier of di-vacancy, with a value of 0.55 eV, corresponds to the $V_2^{2nn} \rightarrow V_2^{2nn}$ path. This is similar to V case for which this mechanism is more favorable than the migration of the mono-vacancy. These results show a different behaviour compared to Fe [21] and W [42] for which the energy barrier of mono-vacancy and di-vacancy are very close.

Diffusion of mixed cluster $\text{He}_1 V_1$ involves firstly the dissociation of He from the vacancy to reach the 1st nearest *T* site (Fig. 10b). Subsequently, the He atom hops via *T* interstitial sites. Simultaneously, the vacancy jumps to first nearest neighbour site (Fig. 10c and d). Finally, He recombines with the mono-vacancy at *S* site (Fig. 10e). The mechanism described above corresponds to the *impeded interstitial mechanism* or *He-vacancy dissociative mechanism* [60,62] where a He atom diffuses through interstitial sites after dissociation from one vacancy and before being retrapped by another vacancy. It leads to an increase of the migration barrier of mono-vacancy by 1.17 eV. Diffusion of He₁V₂ clusters occurs according to the same scenario described above. As for the monovacancy, an increase of the migration barrier is obtained. However, for this case, the increase of migration energy due to He is twice smaller (0.51 eV) for He₁V₂¹ⁿⁿ \rightarrow He₁V₂²ⁿⁿ path than for He₁V₁ case. Contrary to the V case, all paths involving He₁V₂ clusters have almost the same barrier in presence of He. Consequently, He₁V₂ clusters can migrate via these three channels.

Thermal desorption spectra experiments give direct access to dissociation energy defined as the sum of binding energy and migration energy of He atom or vacancy [49]:

$$E^d_{\mathrm{He}/V-\mathrm{He}_n V_m} = E^b_{\mathrm{He}/V-\mathrm{He}_n V_m} + E^m_{\mathrm{He}/V}.$$
(6)

This is the amount of activation energy needed to expel He or vacancy from the cluster. In the previous equation, $E_{\text{He/V}}$ denotes the corresponding energy related to He or vacancy. In Fig. 11 is shown, for V and Ta, the dissociation energy of He and vacancy with respect to the lowest energy configuration of $\text{He}_n V_m$ cluster as a function of n/m ratio. This quantity allows to determine whether a mixed cluster tends to emit a He atom or a vacancy to gain stability, i.e when $\text{E}_{\text{He}}^d > \text{E}_V^d$, the cluster is more likely to emit a vacancy. The presence of a crossover between dissociation energies of He or vacancy shows that the most stable clusters have a n/m ratio of around 0.9 with $\text{E}^d \sim 1.9 \text{ eV}$ in V. This theoretical result is close to experimental results which indicate $\text{E}^d = 1.66 \text{ eV}$ [59]. The fact that the most stable clusters are such that $n \approx m$ is consistent with



Fig. 10. Migration of He₁V₁ cluster in Ta. The initial and final configurations are presented in the frames a and e, respectively. The intermediate steps of migration are presented in the frames b–d. Vacancy, Ta and He atoms are represented with yellow cubes, dark blue and light blue balls respectively. When the He atom is placed in the vacancy site the corresponding vacancy cube is not plotted. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)



Fig. 11. Dissociation energy of He and vacancy from He_nV_m clusters, in V (left panel) and Ta (right panel), as a function of *n*/*m* ratio. Configurations with the lowest formation energy are taken as references.

hypotheses taken to analyse TDS experiments [55] and previous results in Fe [33]. The corresponding quantities for Ta are estimated to ~0.9 *n*/*m* ratio and $E^d \sim 2.5$ eV.

4. Conclusion

We performed first-principle calculations of the formation, binding and migration energy of vacancies in the presence or not of He atoms in bcc V and Ta. In summary, we present our main results:

- interstitial He atoms diffuse through tetrahedral sites in both V and Ta, as in the case of W [38,63].
- for both V and Ta, the formation energy of di-vacancy in V_2^{2nn} configuration is lower than the formation energy of V_2^{1nn} configuration. This tendency is also observed in the VI metals such as Mo and W and in Fe. The di-vacancies in V and Ta have a weak attractive binding energy whereas it is repulsive for group VI metals.
- the effect of He on di-vacancies is to increase the formation energy of the V_2^{1nn} and V_2^{2nn} configurations. This increase is more important for V_2^{2nn} than V_2^{1nn} configuration so that the hierarchy is reversed, i.e. $E_{\text{He}_n V_2^{2nn}}^f > E_{\text{He}_n V_2^{1nn}}^f$ for $n \ge 2$ in V and $n \ge 1$ in Ta. In addition, the binding energy of $\text{He}_n V_2^{1nn}$ to He atom and mono-vacancy is larger than the binding energy of $\text{He}_n V_2^{2nn}$ to He atom and mono-vacancy when *n* increases.
- as general tendency the He atom stabilizes vacancy type clusters and vice versa. This is a trend that was also observed in W [63].
- for the two present studied metals of group *VB*, di-vacancy is more mobile than mono-vacancy. The presence of He atom enhances the migration energy barrier of both mono-vacancy and di-vacancy but also their relative difference.
- in absence of He, di-vacancy diffuses preferentially via $V_2^{2nn} \rightarrow V_2^{2nn}$ path in a 2 steps vacancy dissociation-association process in both V and Ta.
- in the presence of He atom, diffusion of both mono-vacancy and di-vacancy involves dissociation of He atom from the vacancy type cluster following the 'impeded interstitial mechanism' in both V and Ta case. For the di-vacancy diffusion in V, the V₂^{2m}

 $\rightarrow V_2^{2nn}$ path is still favored, but in case of Ta, all paths have the same energy barrier.

• the most stable clusters have a *n/m* ratio about 0.9 with a dissociation energy of 1.9 eV and 2.5 eV for V and Ta, respectively. In the case of W the values are somehow different: the ratio *n/m* is 2 and the dissociation energy is almost 4 eV [38,64]

The present study permits to get insight into the kinetics of the growth of He_nV_m clusters. The energy landscape of the He atoms in the bcc matrix of the V and Ta metals are revealed with some particularities compared to others bcc metals. The results of this paper, are useful, can be used as parameters for kinetic modelling such as object/event kinetic Monte-Carlo or cluster dynamics simulations.

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